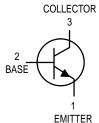
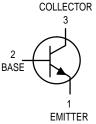
## **Amplifier Transistor** NPN Silicon

## **MPS4124**





#### **MAXIMUM RATINGS**

Rating	Symbol	Value	Unit
Collector-Emitter Voltage	VCE	25	Vdc
Collector-Base Voltage	VCB	30	Vdc
Emitter-Base Voltage	V <sub>EB</sub>	5.0	Vdc
Collector Current — Continuous	IC	200	mAdc
Total Power Dissipation @ T <sub>A</sub> = 25°C Derate above 25°C	PD	625 5.0	mW mW/°C
Total Power Dissipation @ T <sub>C</sub> = 25°C Derate above 25°C	PD	1.5 12	W mW/°C
Operating and Storage Junction Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	-55 to +150	°C

# **CASE 29-04, STYLE 1** TO-92 (TO-226AA)

#### THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	200	°C/W
Thermal Resistance, Junction to Case	$R_{ heta JC}$	83.3	°C/W

#### **ELECTRICAL CHARACTERISTICS** (T<sub>A</sub> = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
OFF CHARACTERISTICS				
Collector-Emitter Breakdown Voltage (I <sub>C</sub> = 1.0 mA, I <sub>B</sub> = 0)	V(BR)CEO	25	_	Vdc
Collector-Base Breakdown Voltage (I <sub>C</sub> = 10 μA, I <sub>E</sub> = 0)	V(BR)CBO	30	_	Vdc
Emitter–Base Breakdown Voltage ( $I_C = 0$ , $I_E = 10 \mu A$ )	V(BR)EBO	5.0	_	Vdc
Collector Cutoff Current (V <sub>CB</sub> = 20 V, I <sub>E</sub> = 0)	ICBO	_	50	nAdc
Emitter Cutoff Current (VEB = 3.0 V, IC = 0)	IEBO	_	50	nAdc

(Replaces MPS4123/D)

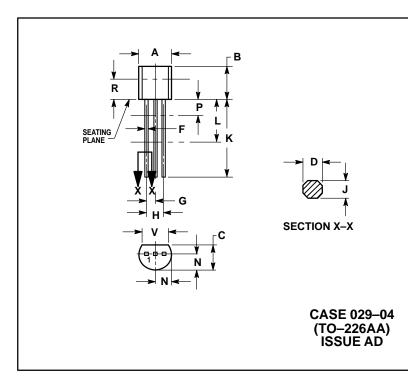


#### **MPS4124**

### **ELECTRICAL CHARACTERISTICS** ( $T_A = 25^{\circ}C$ unless otherwise noted) (Continued)

Characteristic	Symbol	Min	Max	Unit
ON CHARACTERISTICS			•	•
DC Current Gain $(I_C = 2.0 \text{ mA}, V_{CE} = 1.0 \text{ V})$ $(I_C = 50 \text{ mA}, V_{CE} = 1.0 \text{ V})$	hFE	120 60	360 —	_
Collector-Emitter Saturation Voltage (I <sub>C</sub> = 50 mA, I <sub>B</sub> = 5.0 mA)	VCE(sat)	_	0.3	Vdc
Base-Emitter Saturation Voltage (I <sub>C</sub> = 50 mA, I <sub>B</sub> = 5.0 mA)	V <sub>BE</sub> (sat)	_	0.95	Vdc
SMALL-SIGNAL CHARACTERISTICS	•			
Current-Gain — Bandwidth Product (I <sub>C</sub> = 10 mA, V <sub>CE</sub> = 20 V, f = 100 MHz)	fT	170	_	MHz
Output Capacitance (V <sub>CB</sub> = 5.0 V, I <sub>E</sub> = 0, f = 1.0 MHz)	C <sub>ob</sub>	_	4.0	pF
Input Capacitance (V <sub>EB</sub> = 0.5 V, I <sub>C</sub> = 0, f = 1.0 MHz)	C <sub>ib</sub>	_	13.5	pF
Small–Signal Current Gain ( $I_C = 2.0 \text{ mA}$ , $V_{CE} = 1.0 \text{ V}$ , $f = 1.0 \text{ kHz}$ )	h <sub>fe</sub>	120	480	_
Noise Figure (I <sub>C</sub> = 100 $\mu$ A, V <sub>CE</sub> = 5.0 V, R <sub>S</sub> = 1.0 k $\Omega$ , f = 1.0 kHz)	NF	_	5.0	dB

#### **PACKAGE DIMENSIONS**



- NOTES:
  1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
  2. CONTROLLING DIMENSION: INCH.
  3. CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED.
  4. DIMENSION F APPLIES BETWEEN P AND L. DIMENSION D AND J APPLY BETWEEN L AND K MINIMUM. LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

	INCHES		MILLIN	IETERS	
DIM	MIN	MAX	MIN	MAX	
Α	0.175	0.205	4.45	5.20	
В	0.170	0.210	4.32	5.33	
C	0.125	0.165	3.18	4.19	
D	0.016	0.022	0.41	0.55	
F	0.016	0.019	0.41	0.48	
G	0.045	0.055	1.15	1.39	
Н	0.095	0.105	2.42	2.66	
7	0.015	0.020	0.39	0.50	
K	0.500		12.70		
L	0.250		6.35		
N	0.080	0.105	2.04	2.66	
Р		0.100		2.54	
R	0.115		2.93		
٧	0.135		3 43		

STYLE 1: PIN 1. EMITTER

2. BASE 3. COLLECTOR

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MPS4124/D